## Notice of References Cited Application/Control No. 10/622,113 Examiner LI LIU Applicant(s)/Patent Under Reexamination POHJOLA ET AL. Art Unit Page 1 of 1

## U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-5,706,111	01-1998	Morales et al.	398/72
*	В	US-6,434,175	08-2002	Zah, Chung-en	372/20
*	С	US-2004/0252738	12-2004	Hill, Steven E.	372/043
*	D	US-5,940,207	08-1999	Weich et al.	359/333
	Е	US-			
	F	US-			
	G	US-			
	Ι	US-			
	I	US-			
	7	US-			
	K	US-			
	┙	US-			
	М	US-			

## FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	Ν					
	0					
	Р					
	Q					
	R					
	S					
	Т					

## **NON-PATENT DOCUMENTS**

	Non i Alexi Bodolii Ento						
*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)					
*	J	Kim et al: "A Low-Cost WDM Source with ASE Injected Fabry-Perot Semiconductor Laser", IEEE Photonics Technology Letters, Vol. 12, No. 8, August 2000, page 1067-1069					
*	>	Stubkjaer: "Semiconductor Optical Amplifier-Based All-Optical Gates for High-Speed Optical Processing", IEEE Journal on Selected Topics in Quantum Electronics, Vol. 6, No. 6, November/December 2000, pages 1428-1435					
	W						
	×						

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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